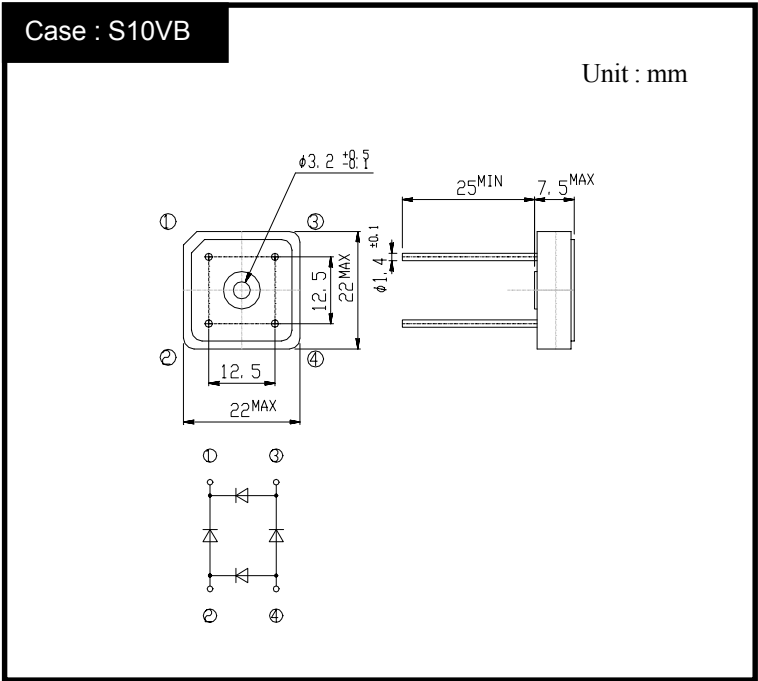


S10VB60

600V 10A

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings

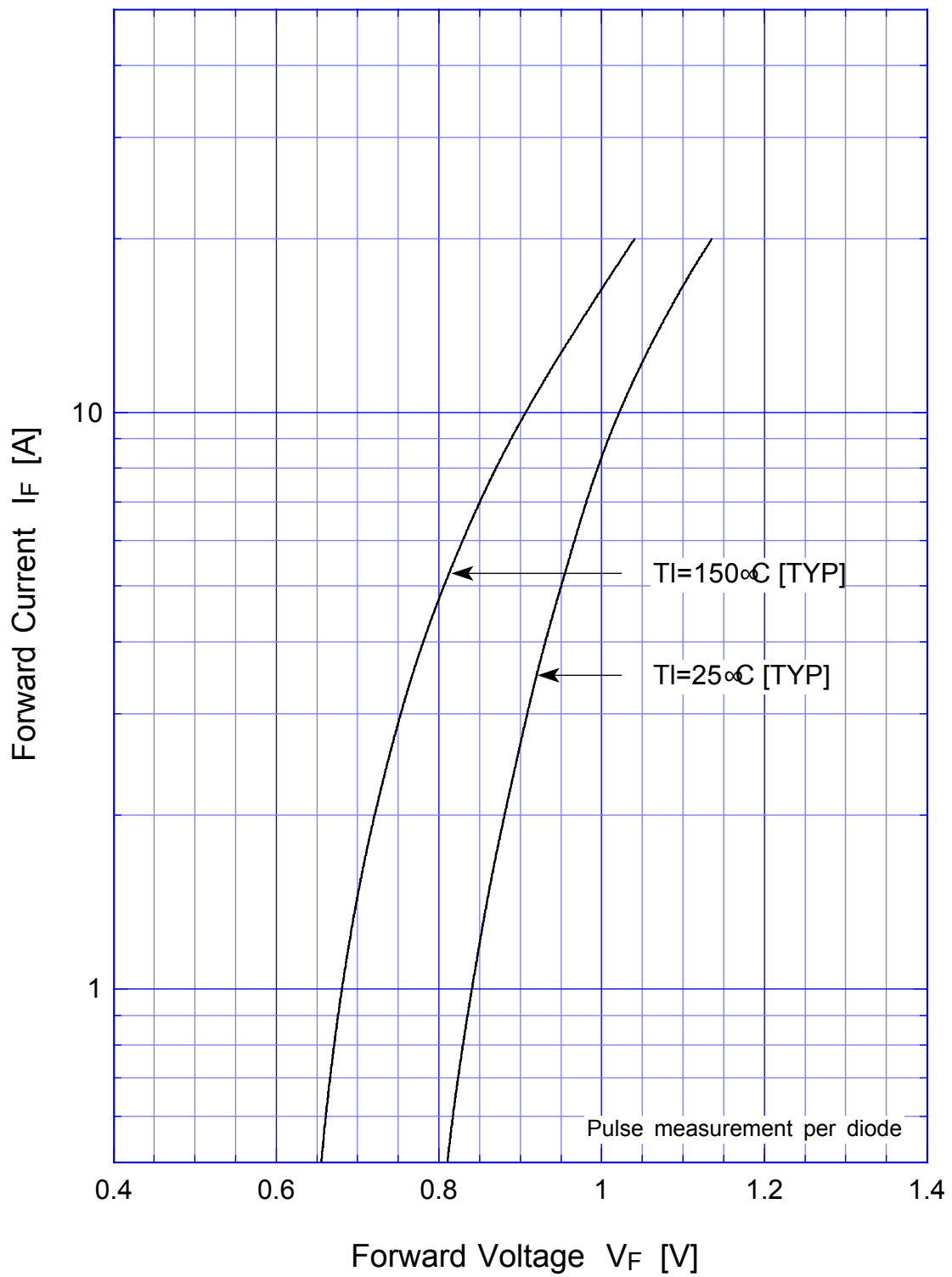
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-40~150	℃
Operating Junction Temperature	Tj		150	℃
Maximum Reverse Voltage	V _{RM}		600	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, Ta=40℃ With heatsink θ fa=2.4℃/W	10	A
		50Hz sine wave, R-load, Ta=40℃ Without heatsink	3.7	
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, Tj=25℃	200	A
Current Squared Time	I ² t	1ms≦t<10ms Tc=25℃	110	A ² s
Dielectric Strength	Vdis	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.5N•m)	0.8	N•m

● Electrical Characteristics (Tl=25℃)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	IF=5A, Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	I _R	VR=VRM, Pulse measurement, Rating of per diode	Max.10	μ A
Thermal Resistance	θ jl	junction to lead	Max.2.8	℃/W

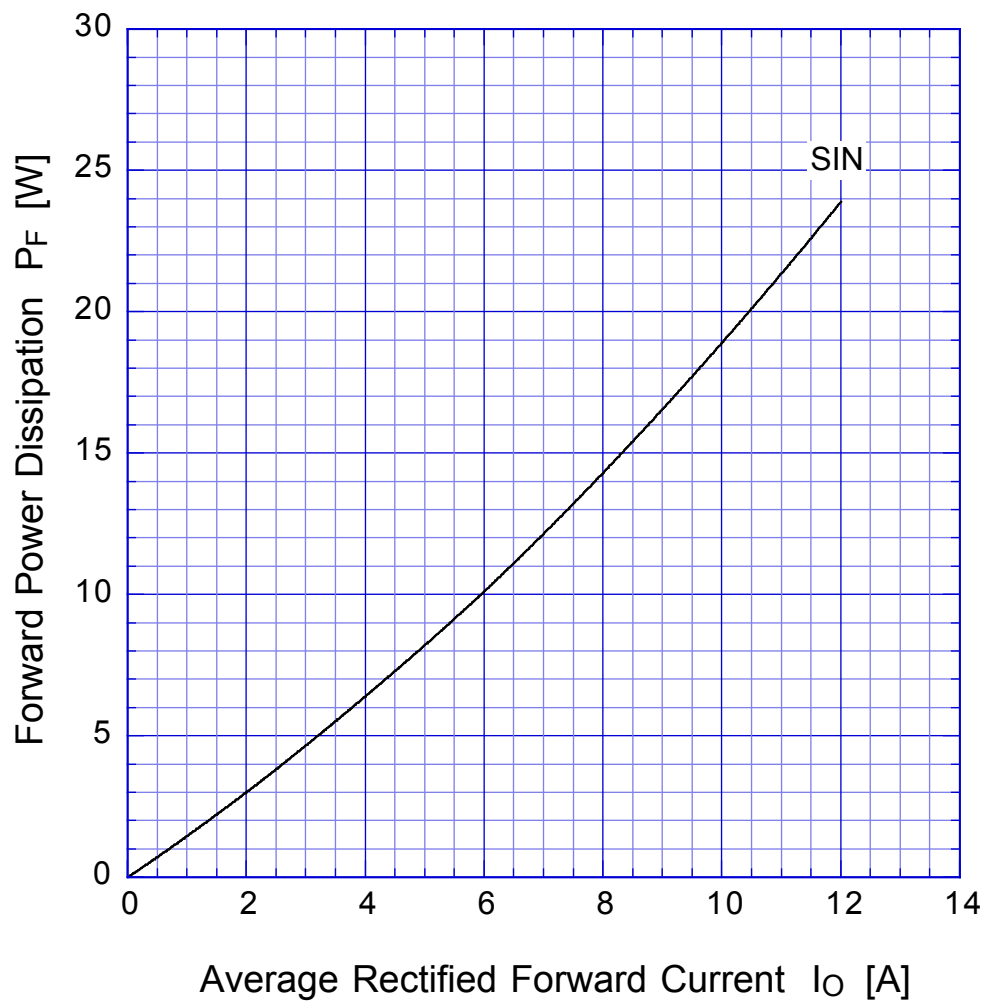
S10VBx

Forward Voltage



S10VBx

Forward Power Dissipation

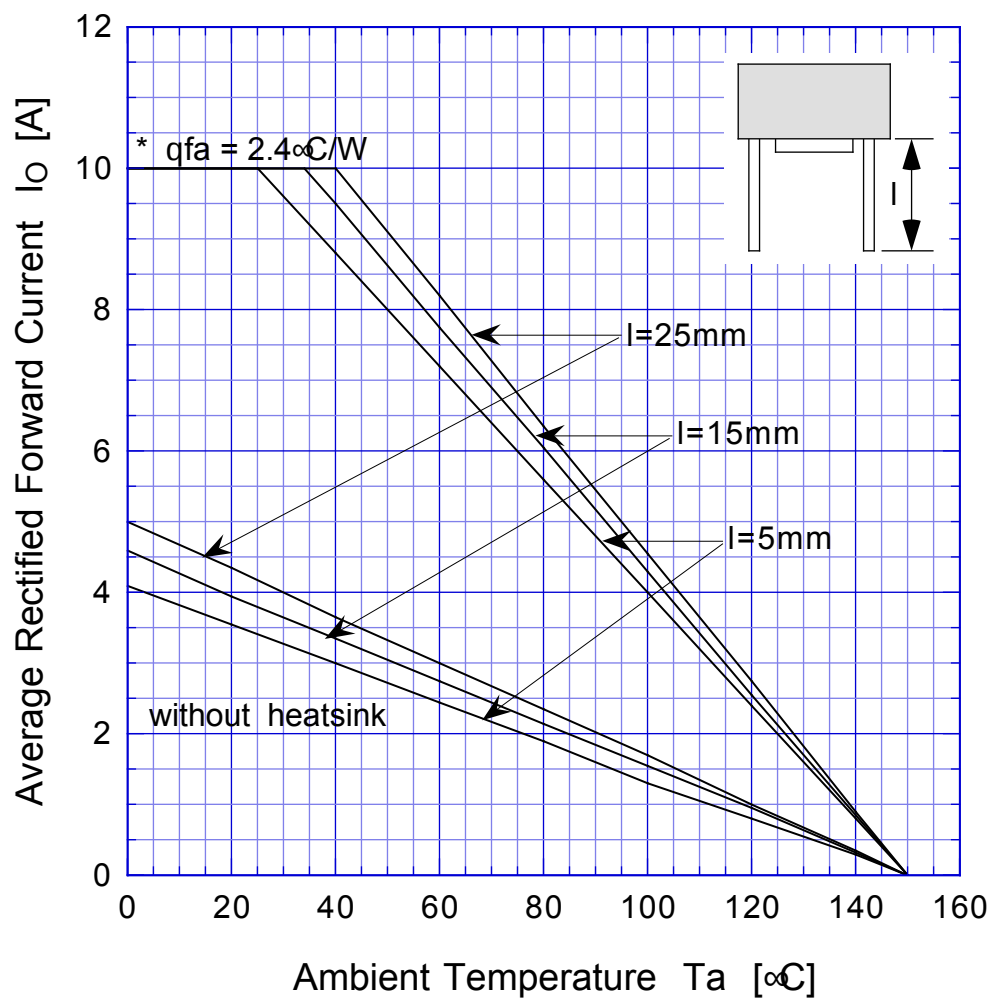


$T_j = 150^\circ\text{C}$

Sine wave

S10VBx

Derating Curve



Sine wave

R-load

Free in air

* with thermal compound, TOR=5kg-cm

S10VBx

Peak Surge Forward Capability

